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<u>Fairchild Semiconductor</u> <u>PN4143</u>

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Discrete POWER & Signal **Technologies**

PN4143



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	800	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		PN4143	=
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
R _{eJC}	Thermal Resistance, Junction to Case	83.3	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	200	°C/W

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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PNP General Purpose Amplifier

(continued)

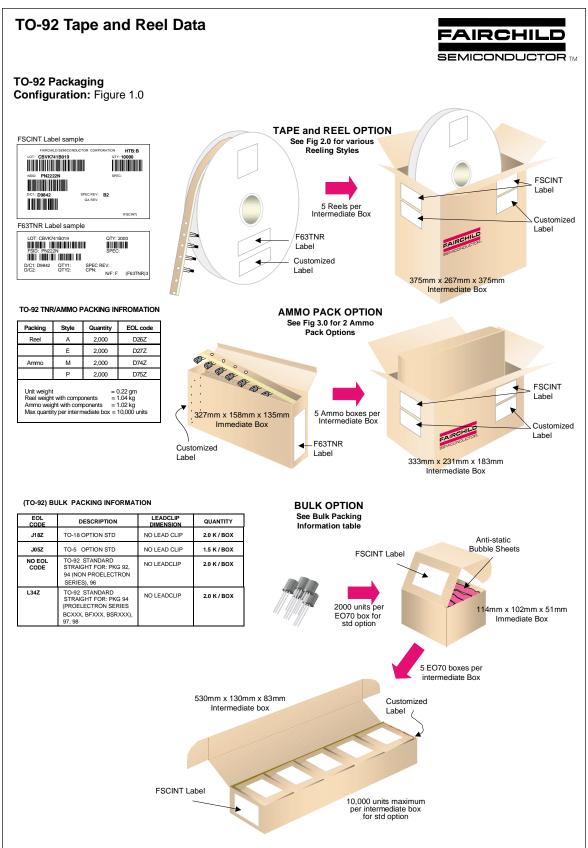
Symbol	Parameter	Test Conditions	Min	Max	Unit
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \mu\text{A}, I_E = 0$	60		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0		V
CEX	Collector Cutoff Current	$V_{CE} = 30 \text{ V}, V_{OB} = 0.5 \text{ V}$		50	nA
BL	Base Cutoff Current	$V_{CE} = 30 \text{ V}, V_{OB} = 0.5 \text{ V}$		50	nA
D _{FE}	RACTERISTICS* DC Current Gain	$V_{CE} = 10 \text{ V}, I_{C} = 100 \mu\text{A}$ $V_{CE} = 10 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 10 \text{ V}, I_{C} = 150 \text{ mA}$	35 50 75 100	300	
/ _{CE(sat)}	Collector-Emitter Saturation Voltage	V _{CE} = 10 V, I _C = 500 mA V _{CE} = 1.0 V, I _C = 150 mA I _C = 150 mA, I _B = 15 mA	30 50	0.4	V
- CE(Sat)		$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		1.6	V
/ _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		1.3 2.6	V
SMALL S	SIGNAL CHARACTERISTICS Output Capacitance	V _{CB} = 10 V, f = 100 kHz		8.0	pF
C _{ib}	Input Capacitance	$V_{EB} = 2.0 \text{ V}, f = 100 \text{ kHz}$		30	pF
Nfe	Small-Signal Current Gain	$I_C = 50 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	2.0		
SWITCHI	NG CHARACTERISTICS				
on	Turn-on Time	$V_{CC} = 30 \text{ V}, I_{C} = 150 \text{ mA},$		45	ns
d	Delay Time	I _{B1} = 15 mA		10	ns
<u>-</u>	Rise Time	1		40	ns
off	Turn-off Time	$V_{CC} = 30 \text{ V}, I_{C} = 150 \text{ mA}$		100	ns
s	Storage Time	$I_{B1} = I_{B2} = 15 \text{ mA}$		80	ns

^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

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Datasheet of PN4143 - TRANS PNP 40V 0.8A TO-92

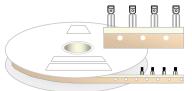
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TO-92 Tape and Reel Data, continued

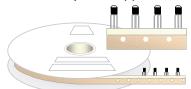
TO-92 Reeling Style Configuration: Figure 2.0





Style "A", D26Z, D70Z (s/h)

Machine Option "E" (J)



Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0

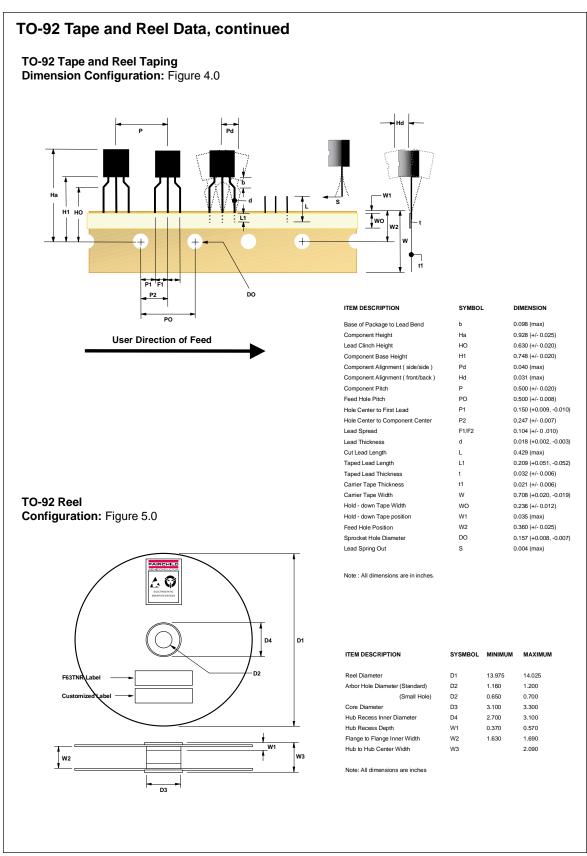


FIRST WIRE OFF IS EMITTER
ADHESIVE TAPE IS ON THE TOP SIDE
FLAT OF TRANSISTOR IS ON BOTTOM

ORDER STYLE
D75Z (P)

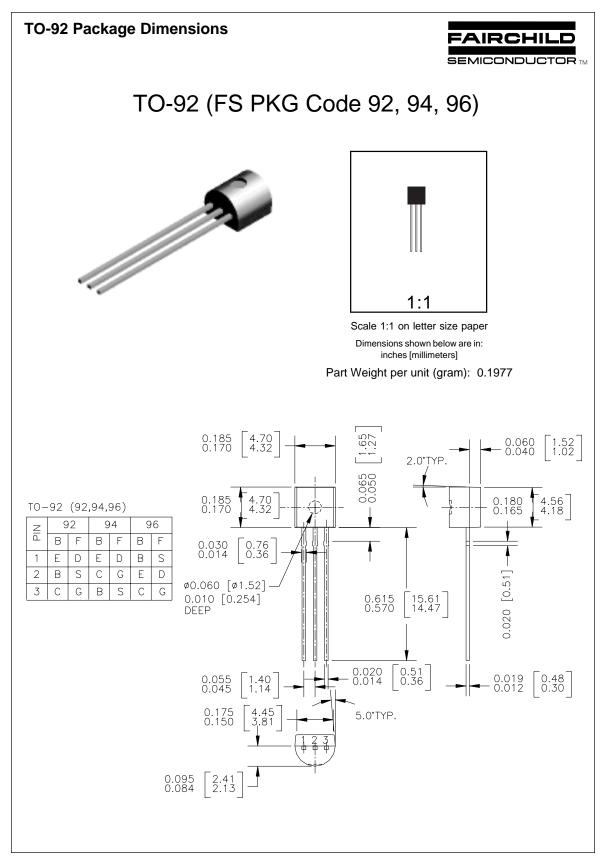
FIRST WIRE OFF IS COLLECTOR (ON PKG. 92)
ADHESIVE TAPE IS ON BOTTOM SIDE
FLAT OF TRANSISTOR IS ON TOP







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